Effect of Isothermal Aging on Ball Shear Strength in BGA Joints with Sn–3.5Ag–0.75Cu Solder

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The ball shear strength of BGA solder joints during isothermal aging was studied with Sn–3.5Ag–0.75Cu solder on three different pads (Cu, electroless Ni–P/Cu, immersion Au/Ni–P/Cu) at temperature between 70 and 170°C for times ranging from 1 to 100 days. The reliability of solder ball attachment was characterized by mechanical ball shear tests. As a whole, the shear strength of BGA joints decreased with increasing temperature and time. The shear strength for both the immersion Au/Ni–P/Cu and electroless Ni–P/Cu pads was consistently higher than that of the Cu pad for all isothermal aging conditions. The fracture surface showed various characteristics depending on aging temperature, time, and the types of BGA pad. The P-rich Ni layer formed at the interface between (Cu, Ni)6Sn5 and Ni–P deposits layer after aging, but fracture at this interface was not the dominant site for immersion Au/Ni–P/Cu and electroless Ni–P/Cu pad.

1. Introduction

Compared to more conventional packages, such as the dual-in line package or the quad-flat-pack package, the ball-grid array (BGA) package has the advantages of having higher input/output terminal density, smaller footprint, and higher reliability.1–3) The BGA package has been successfully applied in many electronic products.4–6) There are an increasing number of higher density BGA substrates that use immersion Au/electroless Ni for the surface finish. The principal advantage of electroless plating is the ability to meet the requirements of increasing in the terminal density. However, there is insufficient space to allow bussing for the more common electrolytic Au/Ni plating.7,8) The contact pads for the solder balls on the BGAs usually have an Au/Ni surface finish. Each layer of metal plated on BGA substrates has its own specific functions. A nickel layer is used as a barrier to prevent copper from diffusing into solder balls, because copper will interact with tin to form a Cu–Sn intermetallic compound. This intermetallic compound will then affect the shear strength of solder balls. Gold is plated on the Ni surface of the ball pads not only to improve the wettability, but also to increase the resistance to corrosion.9,10)

Alternative solder alloys are needed to meet environmental regulations, requirements for greater mechanical reliability, and higher temperature service environments in automobiles and in avionics systems.11,12) Especially, the Sn–Ag and Sn–Ag–Cu alloys are regarded as having the most potential as lead free solder systems.13,14)

During soldering, the solder alloy melts and reacts with the pad to form intermetallic compounds at the interface joints. In addition, it can grow through the solid state reaction below the melting temperature of the solder. While forming a thin intermetallic compound layer, by the reaction between the solder and pad, it is desirable to achieve a good metallurgical bond. At the same time, excessive intermetallic compound growth may have a deleterious effect.15,16)

However, the metallurgical behavior and reliability of BGA joints with Sn–Ag–Cu solder have not been sufficiently studied yet. Therefore, the present work was carried out to investigate the effect of isothermal aging on the reliability of BGA joints with Sn–3.5Ag–0.75Cu solder. Ball shear tests were conducted as a function of the time and temperature for isothermal aging. The interfacial reactions between Sn–3.5Ag–0.75Cu solder and BGA pads with three different surface finishes were also studied.

2. Experimental Procedures

Solder balls used in this study were Sn–3.5Ag–0.75Cu solder with a diameter of 760µm. The BGA substrates used in this study were commercially available, and thermally enhanced BGA substrates with 421 pads, with each pad having a diameter of 640µm. The BGA pads with three different surface finishes in this study were, namely, bare Cu pad, electroless Ni–P/Cu pad with Ni–P layer thickness of 7–8µm, and immersion Au/electroless Ni–P/Cu pad with Ni–P and Au layers of 0.15 and 7–8µm thickness. The electroless Ni plating deposits a mixture of Ni and phosphorous, because of the use of hypophosphite in the chemical reaction for reducing Ni ions. Electroless Ni layers which contain 15 at.%P have an amorphous structure. The temperature of the Ni bath is 88°C and the pH 4.3–4.8. The Au layer is deposited on the Ni–P using an immersion Au bath to prevent the oxidation of Ni. The temperature of the Au bath is 89°C and the pH 5.6–6.2. The solder balls were dipped into flux and then planted on the pads manually and the balls were refloved by using an IR reflow oven (Japan Pulse Labolataries, INC., RF-430-M2). The peak reflow temperature, the highest temperature of a package, was 250°C and the reflow time at which solder balls melt was 120 s. BGA solder joints were then aged isothermally in a convection oven at 70, 120, 150, and 170°C for various times up to about 100 days. SEM (scanning electron microscopy) was used to study the microstructural morphology of solder.
3. Results and Discussion

The SEM micrographs of Figs. 1(a)–(c) show the growth of intermetallic layers at the interface between Sn–3.5Ag–0.75Cu solder and Cu pad. In the as-soldered sample, the Cu₆Sn₅ intermetallic compound located at the solder/Cu pad interface was identified by means of EDX analysis, but Cu₃Sn intermetallic was not found as shown in Fig. 1(a). On the other hand, after isothermal aging, the solder/Cu pad interface exhibited a duplex structure of Cu₆Sn₅ and Cu₃Sn intermetallic (see Figs. 1(b) and (c)).

Figures 1(d)–(f) display a series of SEM micrographs showing the growth of intermetallic layers at the interface between Sn–3.5Ag–0.75Cu solder and immersion Au/Ni–P/Cu pads. During soldering, all Au layer on the pad is dissolved into the bulk solder, and the Ni–P layer comes in contact with the molten solder. The Ni atoms diffused inward into the solder, forming only a Ni–Sn intermetallics and P is expelled from the Ni–Sn intermetallic layer. 17) In the case of Ni and Sn interaction, the chunky and needle type Ni₃Sn₄ intermetallics formed at the solder/electroless Ni–P interface is known to be the primary intermetallic compound. 18) According to previous work by Zeng et al., 19) the (Cu, Ni)₆Sn₅ intermetallic compound was formed in the coupled of electroless Ni–P/Sn–3.8Ag–0.7Cu solder. The (Cu, Ni)₆Sn₅ intermetallic compound in this work is formed between the solder and the electroless Ni–P deposits, which satisfy the report of Zeng...
et al.\textsuperscript{20} The Cu of Sn–3.5Ag–0.75Cu solder can diffuse into the Ni–P deposit during soldering and aging. It is concluded that the formation of (Cu, Ni)$_6$Sn$_5$ intermetallic may be due to segregation of Cu between the solder and Ni–P deposit. The Ni concentration in the (Cu, Ni)$_6$Sn$_5$ intermetallic is 7–9 at%, which is expected because Ni and Cu have solid solution in the Cu–Ni binary phase diagram.\textsuperscript{20} Figure 1 also reveals that both the Cu$_6$Sn$_5$ and (Cu, Ni)$_6$Sn$_5$ intermetallic layers thicken, from about 1µm of Cu$_6$Sn$_5$ and 0.5µm of (Cu, Ni)$_6$Sn$_5$ in as-soldered joints to about 12.4µm of Cu–Sn (Cu$_6$Sn$_5$ + Cu$_3$Sn) and 4.7µm of (Cu, Ni)$_6$Sn$_5$ in joints aged at 150°C for 100 days. After significant aging, the interface between the intermetallic compound and bulk solder becomes smoother. This observation is significant, since it is known that a smooth intermetallic/solder interface, as opposed to a rough surface, degrades the mechanical properties of the joint due to the decreased resistance to shear along the interface. Except for the as-soldered joint, Ag$_3$Sn intermetallics are present in the bulk solder and in the intermetallic layer.

Figure 2 shows the variation of shear strength with the time and temperature, and various types of BGA pad surface finishes (bare Cu, electroless Ni–P/Cu and immersion Au/Ni–P/Cu pads). The shear strength decreased with the increasing temperature and time irrespective of the deposited layer. A significant decrease in shear strength was noticed for each type of BGA pad after 15 days of isothermal aging. It can be seen from the test results that the shear strengths decrease by 25.3, 23.7 and 20.4% after 100 days of aging at 150°C compared to the strengths measured after as-soldered for Cu pad, electroless Ni–P/Cu pad and immersion Au/Ni–P/Cu pads. It was noticed that the shear strength for both the immersion Au/Ni–P/Cu and electroless Ni–P/Cu pads was consistently higher than that of the Cu pads for all aging conditions. After as-soldered, the shear strengths were measured as 150.5, 182.2 and 179.8 mN for Cu pad, electroless Ni–P/Cu pad and immersion Au/Ni–P/Cu pad, respectively. After aging at 150°C for 100 days, the shear strength changed to 112.4, 139.1 and 143.2 mN for the above pads. Similar to the isothermal aging conditions, the ball shear strengths of immersion Au/Ni–P/Cu pads and electroless Ni–P/Cu pads were very close. Ball shear strength values of the Cu pads were relatively lower than those of the immersion Au/Ni–P/Cu pads and electroless Ni–P/Cu pads. As tests went on, the shear strength of the solder ball decreased approximately parabolic with the duration of the test for all three types of BGA pads. After isothermal aging, the fracture surface showed various characteristics depending on aging temperature, aging time and the types of BGA pad.

Figure 3 shows the fracture surface of BGA Cu, electroless Ni–P/Cu and immersion Au/Ni–P/Cu pad with Sn–3.5Ag–0.75Cu solder before and after aging at 150°C for 100 days. For Cu BGA pad, the ball shear initially occurred through the solder ball but changed to brittle fracture at the interface between the solder ball and the intermetallic region, within the Cu$_6$Sn$_5$ intermetallic layer and between the Cu$_6$Sn$_5$ and Cu$_3$Sn$_2$ intermetallic after isothermal aging at 150°C for 100 days. For immersion Au/Ni–P/Cu and electroless Ni–P/Cu BGA pad, all failures were observed at the solder bulk side and not at the interface, and showed more ductile fracture mode than those of Cu pads. The shear strength of BGA Cu pad is lower than that on either the immersion Au/Ni–P/Cu or electroless Ni–P/Cu pad, as evidenced by the results in Fig. 2. In the ball shear test, fracture occurs at either interface or in the region with the lowest shear strength. On the Cu pad, after isothermal aging, where two continuous intermetallic compound layers (Cu$_6$Sn$_5$ and Cu$_3$Sn) form, the fracture tends to occur at their interface. It is found that the shear strength between the Cu$_6$Sn$_5$ and Cu$_3$Sn is lower than that between the solder and Cu$_6$Sn$_5$ intermetallic. But when the immersion Au/Ni–P/Cu and electroless Ni–P/Cu pads does not form two continuous intermetallic compound layers, the shear strength decreases due to the coarsening of microstructure. This explains why the shear strength between solder and (Cu, Ni)$_6$Sn$_5$ is higher than that between the Cu$_6$Sn$_5$ and solder as well as the Cu$_6$Sn$_5$ and Cu$_3$Sn intermetallic.
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Figure 3 Fracture surface after ball shear test for solder/Cu pad joint (a), (b), solder/electroless Ni-P/Cu pad joint (c), (d), and immersion Au/Ni-P/Cu joint (e), (f): as-soldered (a), (c), and (e) and after aging at 150°C for 100 days (b), (d), and (f).

Figure 4 shows the fracture surface for Cu BGA pad joints with its EDX analysis after aging at 150°C for 100 days. The fracture occurs at the interface between the solder and Cu<sub>6</sub>Sn<sub>5</sub> intermetallic as well as the Cu<sub>6</sub>Sn<sub>5</sub> and Cu<sub>3</sub>Sn intermetallic. In the EDX analysis, the Cu<sub>6</sub>Sn<sub>5</sub> and Cu<sub>3</sub>Sn were detected. The fracture plane largely follows the Cu<sub>6</sub>Sn<sub>5</sub>/Cu<sub>3</sub>Sn intermetallic layer also appear in the fracture surface. This result suggests relatively weak bonding at the Cu<sub>6</sub>Sn<sub>5</sub>/Cu<sub>3</sub>Sn interface, a conclusion that is supported by the different crystal structure of the two intermetallics.

Also, a thick intermetallic compound layer results in mechanical failure due to volume shrinkage during the transformation from solid phase (Sn and Cu) to the intermetallic compounds. A thick intermetallic compound layer poses potential reliability issues due to an 8.5% and 5% volume shrinkage during the transformation from solid phase to the Cu<sub>3</sub>Sn and Cu<sub>6</sub>Sn<sub>5</sub> intermetallics.

As shown in Fig. 1, with 100 days of aging at 150°C, the Cu–Sn(Cu<sub>6</sub>Sn<sub>5</sub> + Cu<sub>3</sub>Sn) intermetallic thickness increases by 12.4 µm, but the (Cu, Ni)<sub>6</sub>Sn<sub>5</sub> intermetallic thickness only by 4.7 µm. The thickness of the Cu–Sn(Cu<sub>6</sub>Sn<sub>5</sub> + Cu<sub>3</sub>Sn) intermetallic increases faster than that of the (Cu, Ni)<sub>6</sub>Sn<sub>5</sub> intermetallic. This would create a large internal strain, so the fracture occurs either at the interface between the Cu<sub>6</sub>Sn<sub>5</sub> and Cu<sub>3</sub>Sn intermetallics or within the Cu<sub>6</sub>Sn<sub>5</sub> intermetallic.

Figure 5 shows the SEM micrographs of the interface between solder and immersion Au/Ni-P/Cu pad after aging at 150°C for 100 days. The back-scattered electron imaging of SEM was used to provide more distinguishable boundaries of the interfacial intermetallic layer. In the results of EDX analysis, two other layers were observed between the solder and Ni-P deposit. A P-rich Ni layer was found immediately adjacent to Ni-P deposits. The (Cu, Ni)<sub>6</sub>Sn<sub>5</sub> intermetallic was
detected between the P-rich Ni layer and solder. The growth of (Cu, Ni)₆Sn₅ intermetallic results in a P-rich Ni layer underneath the (Cu, Ni)₆Sn₅ intermetallic. The electroless Ni–P deposits used in this study contains about 15 at% P, and the P content in the P-rich Ni layer increases to about 25 at% after 100 days of aging at 150°C. This P-rich Ni layer has been accused of causing the brittle fracture of solder joints, but it was not the dominant failure site for immersion Au/Ni–P/Cu and electroless Ni–P/Cu pads.

During aging, it was expected that Au atoms were diffused back to the interface between solder and intermetallic compound and resulted in the decreasing of bonding strength. Ductility loss of Sn base solder due to the presence of gold is often called gold embrittlement and cited as a reason for failure of solder joints. Also, Mei et al. reported that Au–Sn intermetallics caused embrittlement in BGA joints. However, Au was not found remaining at the interface of the BGA pad and solder ball due to the limited spatial resolution of the SEM. A possible explanation is that Au–Sn intermetallics were too rare to detect, since the Au plating is so thin for immersion Au/Ni–P/Cu BGA pads. As shown in Figs. 3(e) and (f), on the immersion Au/Ni–P/Cu pads, all failures are observed as only the ductile fracture inside the solder ball. Also, Syed reported that the ball shear strength favors Sn–Ag–Cu solder over Sn–Pb solder.

From the results above, it is concluded that using Sn–3.5Ag–0.75Cu solder can possibly eliminate the Au embrittlement issue.

4. Conclusion
During isothermal aging, the fracture surface and the ball shear strength of Sn–3.5Ag–0.75Cu solder balls on BGA pads with three different surface finishes were investigated. The following conclusions were obtained:

1. Irrespective of the deposited layer, the shear strength decreased with increasing temperature and time. Especially, the Cu–Sn(Cu₆Sn₅ + Cu₃Sn) intermetallic was the main contributor of solder joint failure due to a thicker Cu–Sn(Cu₆Sn₅ + Cu₃Sn) intermetallic compound layer with larger volume shrinkage after isothermal aging.

2. The Ni–P deposits layer serve as a diffusion barrier, limiting the Cu from diffusing into the solder and forming the brittle Cu–Sn intermetallics. Also, the fracture at P-rich Ni layer was not the dominant failure site for immersion Au/Ni–P/Cu and electroless Ni–P/Cu pads.

3. During the aging, on the Cu pad, the failure mode gradually changes from ductile fracture in solder to brittle fracture (i) at the interface between solder and intermetallic compound, (ii) within the intermetallic compound and (iii) between two intermetallic compound layers. However, the failure mode of a solder ball with electroless Ni–P/Cu and immersion Au/Ni–P/Cu pads is different from a Cu pad. After long aging times, all failures were observed as only ductile fracture inside the solder ball. This indicates that using Sn–3.5Ag–0.75Cu solder can possibly eliminate the Au embrittlement issue.

4. The structure of solder/immersion Au/Ni–P/Cu BGA pad interface after aging at 150°C for 100 days, from solder to the BGA pads, consists of a bulk solder, (Cu, Ni)₆Sn₅ intermetallic, and a P-rich Ni layer.
metallic layer, P-rich Ni layer, an amorphous Ni–P deposits with 15 at% phosphorous, and Cu pad. On the other hand, the solder/Cu pad interface exhibits a duplex structure of Cu₅Sn₃ and Cu₃Sn intermetallic.

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